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### VS-10ETF10FP-M3, VS-10ETF12FP-M3

**Vishay Semiconductors** 

# Fast Soft Recovery Rectifier Diode, 10 A



TO-220 FullPAK 2L

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	10 A			
V <sub>R</sub>	1000 V, 1200 V			
V <sub>F</sub> at I <sub>F</sub>	1.33 V			
I <sub>FSM</sub>	140 A			
t <sub>rr</sub>	80 ns			
T <sub>J</sub> max.	150 °C			
Snap factor	0.6			
Package	TO-220 FullPAK 2L			
Circuit configuration	Single			

#### **FEATURES**

- Glass passivated pellet chip junction
- 150 °C max. operation junction temperature • Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- UL pending
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **APPLICATIONS**

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

#### DESCRIPTION

The VS-10ETF1..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
V <sub>RRM</sub>		1000, 1200	V			
I <sub>F(AV)</sub>	Sinusoidal waveform	10	٨			
I <sub>FSM</sub>		140	A			
t <sub>rr</sub>	1 A, 100 A/μs	80	ns			
V <sub>F</sub>	10 A, T <sub>J</sub> = 25 °C	1.33	V			
TJ		-40 to +150	°C			

VOLTAGE RATINGS							
PART NUMBER	T NUMBER V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V		I <sub>RRM</sub> AT 150 °C mA				
VS-10ETF10FP-M3	1000 1100		4				
VS-10ETF12FP-M3	1200	1300	4				

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ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	$T_C = 95$ °C, 180° conduction half sine wave	10	
Maximum peak one cycle		10 ms sine pulse, rated $V_{\text{RRM}}$ applied	115	А
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	140	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated $V_{RRM}$ applied	66	A <sup>2</sup> s
		10 ms sine pulse, no voltage reapplied	94	A-S
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	940	A²√s

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V <sub>FM</sub>	10 A, T <sub>J</sub> = 25 °C		1.33	V
Forward slope resistance	r <sub>t</sub>	T <sub>J</sub> = 150 °C		22.9	mΩ
Threshold voltage	V <sub>F(TO)</sub>			0.96	V
Maximum reverse leakage current		T <sub>J</sub> = 25 °C	$V_{R}$ = rated $V_{RRM}$	0.1	mA
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C		4	

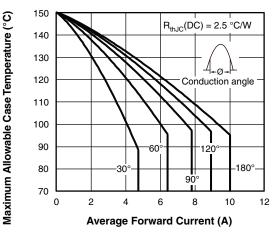
RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t <sub>rr</sub>	L at 10 A	310	ns	I <sub>FM</sub>
Reverse recovery current	I <sub>rr</sub>	l <sub>F</sub> at 10 A <sub>pk</sub> 25 Α/μs 25 °C	4.7	А	
Reverse recovery charge	Q <sub>rr</sub>	25 0	1.05	μC	$\frac{\text{dir}}{\text{dt}}$
Snap factor	S		0.6		

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C
Maximum thermal resistar junction to case	nce	R <sub>thJC</sub>	DC operation	2.5	
Maximum thermal resistar junction to ambient	nce	R <sub>thJA</sub>		62	°C/W
Typical thermal resistance case to heatsink	, ,	R <sub>thCS</sub>	Mounting surface, smooth, and greased	0.5	
Approximate weight				2	g
Approximate weight				0.07	oz.
minimur				6 (5)	kgf ⋅ cm
Mounting torque maxi	maximum			12 (10)	(lbf ⋅ in)
Marking device			Case style TO-220 FullPAK 2L	10ETF10FP 10ETF12FP	

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Fig. 1 - Current Rating Characteristics

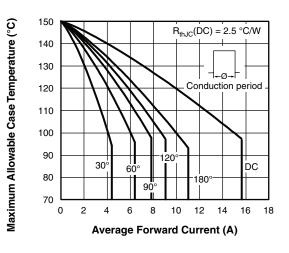


Fig. 2 - Current Rating Characteristics

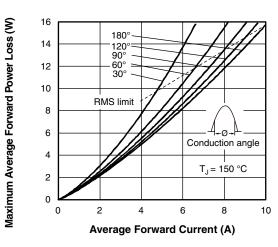


Fig. 3 - Forward Power Loss Characteristics

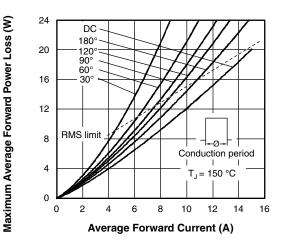
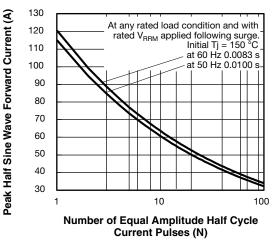
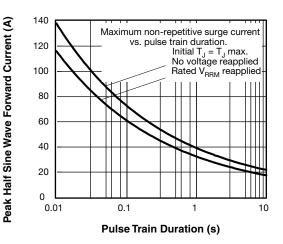
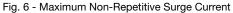


Fig. 4 - Forward Power Loss Characteristics









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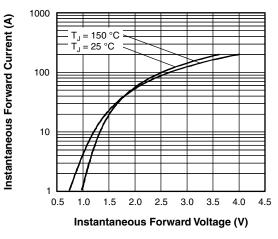


Fig. 7 - Forward Voltage Drop Characteristics

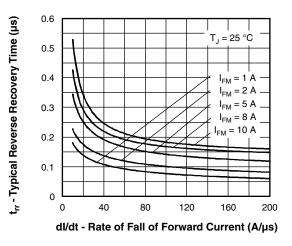


Fig. 8 - Recovery Time Characteristics,  $T_J = 25 \ ^{\circ}C$ 

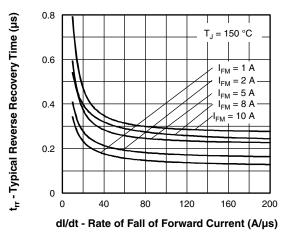


Fig. 9 - Recovery Time Characteristics,  $T_J$  = 150  $^\circ\text{C}$ 

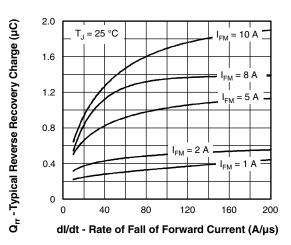
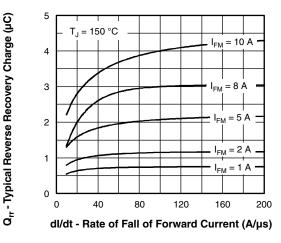
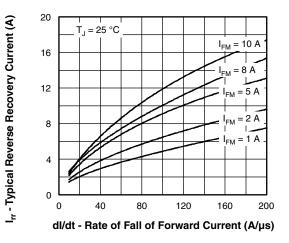
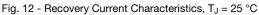


Fig. 10 - Recovery Charge Characteristics,  $T_J = 25 \ ^{\circ}C$ 









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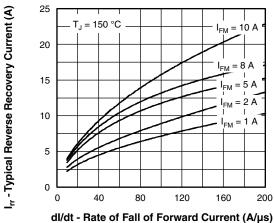
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ulut - hate of Fail of Forward Current (A/µS)

Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C

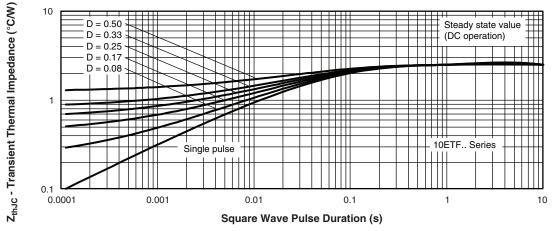


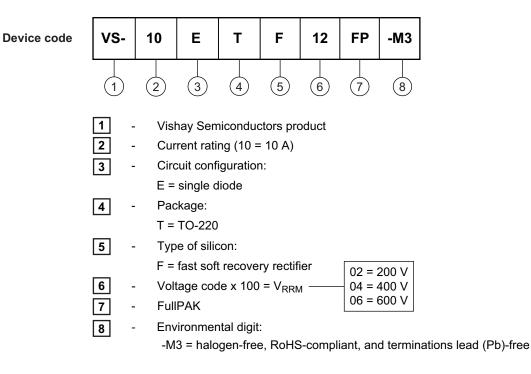
Fig. 14 - Thermal Impedance Z<sub>thJC</sub> Characteristics



## VS-10ETF10FP-M3, VS-10ETF12FP-M3

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#### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10ETF10FP-M3	50	1000	Antistatic plastic tubes			
VS-10ETF12FP-M3	50	1000	Antistatic plastic tubes			

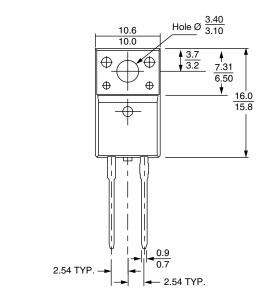
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?96157				
Part marking information	www.vishay.com/doc?95392			

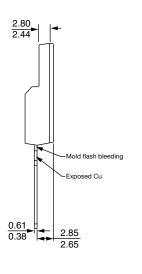


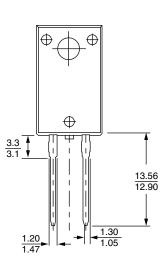
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# 2L TO-220 FullPAK

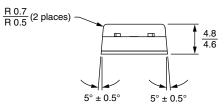
#### **DIMENSIONS** in millimeters







Bottom view





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